

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an equif prese

May 2017

FOD814 Series, FOD817 Series 4-Pin DIP Phototransistor Optocouplers

Features

- AC Input Response (FOD814)
- Current Transfer Ratio in Selected Groups: FOD814: 20–300% FOD817: 50–600% FOD814A: 50–150% FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817A: 80–1609
 FOD817

FOD817: 50–600% FOD817A: 80–160% FOD817B: 130–260% FOD817C: 200–400% FOD817D: 300–600%

- Minimum BV_{CEO} of 70 V Guaranteed
- Safety and Regulatory Approvals
 - UL1577, 5,000 $\ensuremath{\mathsf{VAC}_{\mathsf{RMS}}}$ for 1 Minute
 - DIN EN/IEC60747-5-5

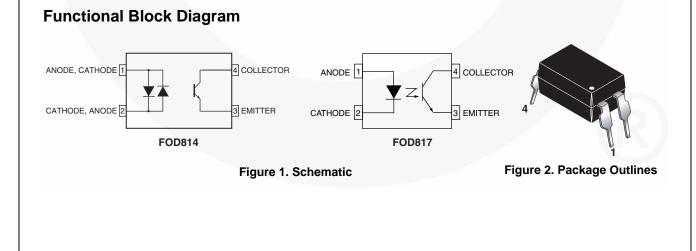
Applications

FOD814 Series

- AC Line Monitor
- Unknown Polarity DC Sensor
- Telephone Line Interface
- FOD817 Series
- Power Supply Regulators
- Digital Logic Inputs
- Microprocessor Inputs

Description

The FOD814 consists of two gallium arsenide infrared emitting diodes, connected in inverse parallel, driving a silicon phototransistor output in a 4-pin dual in-line package. The FOD817 Series consists of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a 4-pin dual in-line package.



Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter	Characteristics	
Installation Classifications per DIN VDE	< 150 V _{RMS}	I–IV
0110/1.89 Table 1, For Rated Mains Voltage	< 300 V _{RMS}	I–III
Climatic Classification	30/110/21	
Pollution Degree (DIN VDE 0110/1.89)	2	
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V	Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with t _m = 10 s, Partial Discharge < 5 pC	1360	V _{peak}
V _{PR}	Input-to-Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ s, Partial Discharge < 5 pC	1560	V _{peak}
V _{IORM}	Maximum Working Insulation Voltage	850	V _{peak}
V _{IOTM}	Highest Allowable Over-Voltage	8000	V _{peak}
	External Creepage	≥ 7	mm
	External Clearance	≥ 7	mm
	External Clearance (for Option W, 0.4" Lead Spacing)	≥ 10	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.4	mm
Τ _S	Case Temperature ⁽¹⁾	175	°C
I _{S,INPUT}	Input Current ⁽¹⁾	400	mA
P _{S,OUTPUT}	Output Power ⁽¹⁾	700	mW
R _{IO}	Insulation Resistance at T_S , $V_{IO} = 500 V^{(1)}$	> 10 ¹¹	Ω

Note:

1. Safety limit values - maximum values allowed in the event of a failure.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^{\circ}C$ Unless otherwise specified.

Cumbal	Devenueder	Va	lue	Unit	
Symbol	Parameter	FOD814	FOD817		
Total Device					
T _{STG}	Storage Temperature	-55 to	o +150	°C	
T _{OPR}	Operating Temperature	-55 to +105	-55 to +110	°C	
TJ	Junction Temperature	-55 to	+125	°C	
T _{SOL}	Lead Solder Temperature	260 for 1	0 seconds	°C	
θ_{JC}	Junction-to-Case Thermal Resistance	2	10	°C/W	
P _{TOT}	Total Device Power Dissipation	200		mW	
EMITTER					
١ _F	Continuous Forward Current	±50	50	mA	
V _R	Reverse Voltage	6		V	
P	Power Dissipation	70		mW	
PD	Derate Above 100°C	1.7		mW/°C	
DETECTOR					
V _{CEO}	Collector-Emitter Voltage	7	0	V	
V _{ECO}	Emitter-Collector Voltage	6		V	
Ι _C	Continuous Collector Current	50		mA	
Р	Collector Power Dissipation	1	50	mW	
P _C	Derate Above 90°C	2	.9	mW/°C	

Electrical Characteristics

 $T_A = 25^{\circ}C$ unless otherwise specified.

Individual Component Characteristics

Symbol	Parameter	Device	Test Conditions	Min.	Тур.	Max.	Unit	
EMITTER				•			•	
	– 137 k	FOD814	$I_F = \pm 20 \text{ mA}$		1.2	1.4	V	
V _F	Forward Voltage	FOD817	I _F = 20 mA		1.2	1.4	v	
I _R	Reverse Current	FOD817	V _R = 4.0 V			10	μA	
C	FOL		V = 0, f = 1 kHz		50	250	ъĘ	
C _t Terminal Capacitance		FOD817	V = 0, f = 1 kHz		30	250	pF	
DETECTO	DR				•		•	
1	Collector Dark Current	FOD814	$V_{CE} = 20 \text{ V}, I_F = 0$			100	5	
ICEO	Collector Dark Current	FOD817	$V_{CE} = 20 \text{ V}, I_F = 0$			100	nA	
	Collector-Emitter Breakdown	FOD814	$I_{\rm C} = 0.1 \text{ mA}, I_{\rm F} = 0$	70			V	
BV _{CEO}	Voltage	FOD817	$I_{\rm C} = 0.1 \text{ mA}, I_{\rm F} = 0$	70			v	
D\/	Emitter-Collector Breakdown	FOD814	$I_{E} = 10 \ \mu A, I_{F} = 0$	6			V	
BV _{ECO}	Voltage	FOD817	I _E = 10 μA, I _F = 0	6				

DC Transfer Characteristics

Symbol	Parameter	Device	Test Conditions	Min.	Тур.	Max.	Unit
		FOD814	$L = 1 m \Lambda V = 5 V$	20		300	
		FOD814A	$I_F = \pm 1 \text{ mA}, V_{CE} = 5 \text{ V}$	50		150	
		FOD817		50		600	
CTR	Current Transfer Ratio ⁽²⁾	FOD817A		80		160	%
		FOD817B	$I_{F} = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	130		260	
		FOD817C		200		400	
		FOD817D		300		600	
V.	Collector-Emitter Saturation	FOD814	$I_F = \pm 20 \text{ mA}, I_C = 1 \text{ mA}$		0.1	0.2	v
V _{CE(SAT)}	Voltage	FOD817	$I_{\rm F} = 20$ mA, $I_{\rm C} = 1$ mA		0.1	0.2	v

AC Transfer Characteristics

Symbol	Parameter	Device	Test Conditions	Min.	Тур.	Max.	Unit
f _C	Cut-Off Frequency	FOD814		15	80	2	kHz
t _r	Response Time (Rise)	FOD814, FOD817	$V_{CE} = 2 \text{ V}, \text{ I}_{C} = 2 \text{ mA},$ R ₁ = 100 $\Omega^{(3)}$		4	18	μs
t _f	Response Time (Fall)	FOD814, FOD817	$R_{L} = 100 \ \Omega^{(3)}$		3	18	μs

Notes:

2. Current Transfer Ratio (CTR) = $I_C / I_F x 100\%$.

3. For test circuit setup and waveforms, refer to page 7.

Electrical Characteristics (Continued)

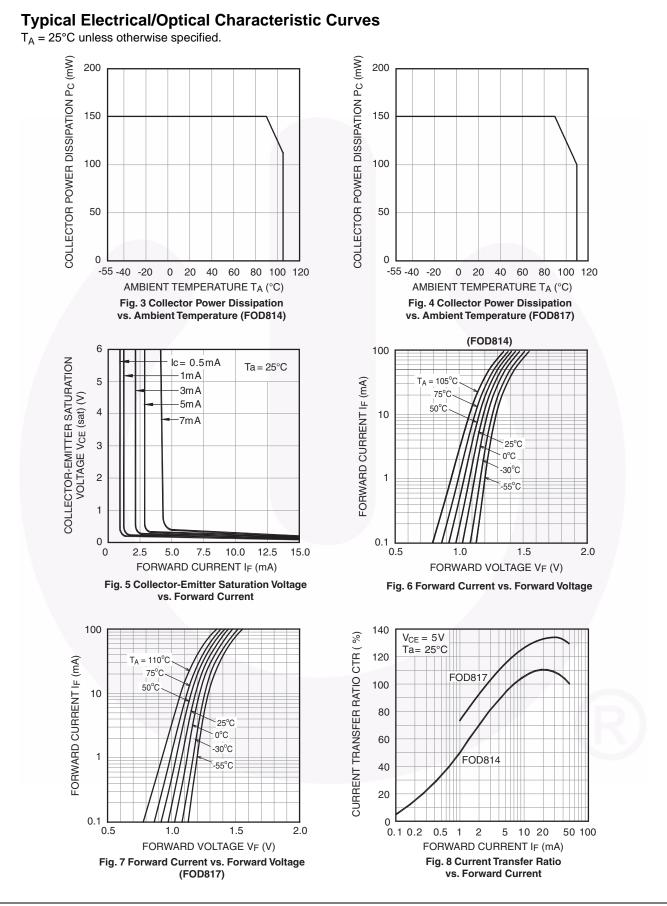
 $T_A = 25^{\circ}C$ unless otherwise specified.

Isolation Characteristics

Symbol	Parameter	Device	Test Conditions	Min.	Тур.	Max.	Unit
V _{ISO}	Input-Output Isolation Voltage ⁽⁴⁾	FOD814, FOD817	$ f = 60 \text{ Hz}, t = 1 \text{ minute}, \\ I_{I-O} \leq 2 \mu A $	5000			VAC _{RMS}
R _{ISO}	Isolation Resistance	FOD814, FOD817	V _{I-O} = 500 V _{DC}	5x10 ¹⁰	1x10 ¹¹		Ω
C _{ISO}	Isolation Capacitance	FOD814, FOD817	$V_{I-O} = 0, f = 1 MHz$		0.6	1.0	pf

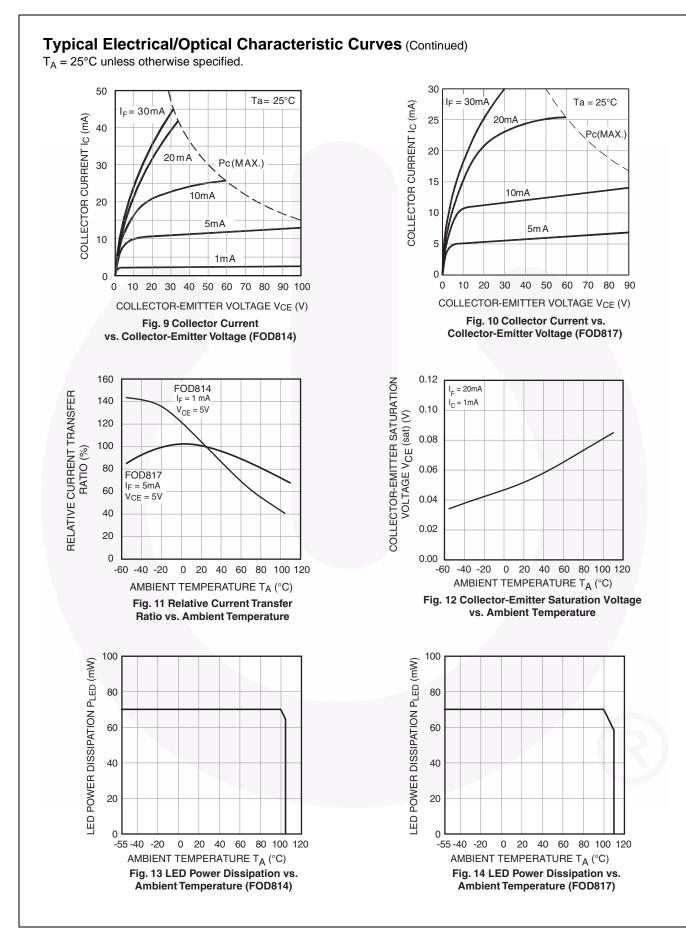
Note:

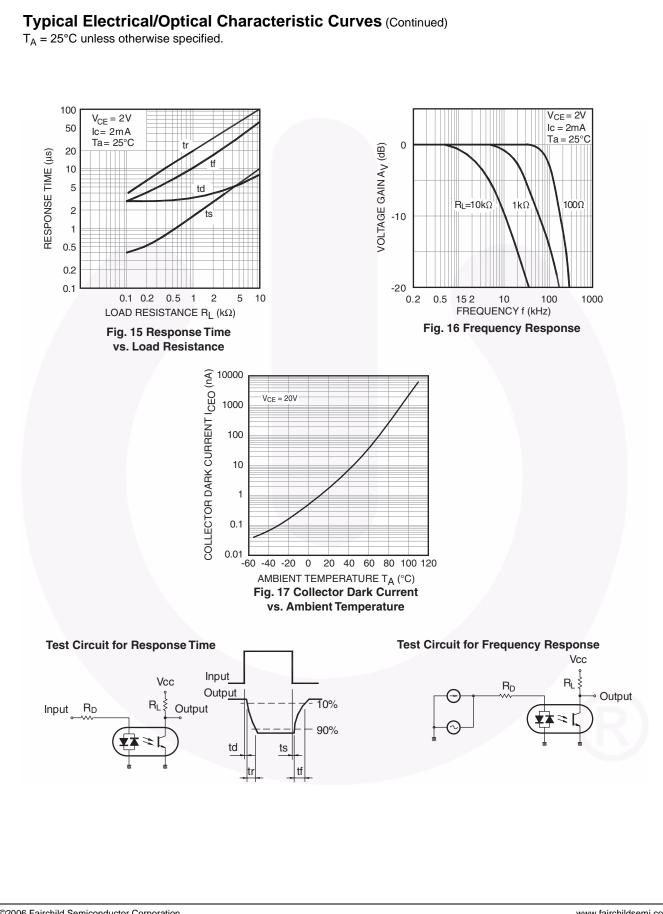
4. For this test, Pins 1 and 2 are common, and Pins 3 and 4 are common.



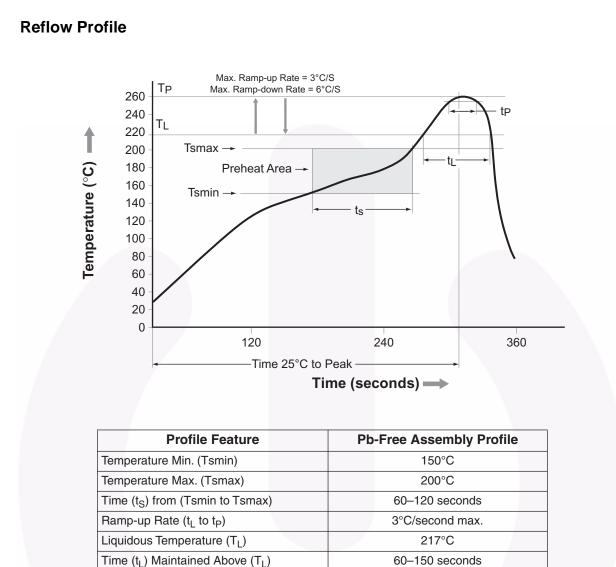
6







8



60	_
9	

FOD814 Series, FOD817 Series — 4-Pin DIP Phototransistor Optocouplers

Figure 20. Reflow Profile

Peak Body Package Temperature Time (t_P) within 5°C of 260°C

Time 25°C to Peak Temperature

Ramp-down Rate (T_P to T_L)

260°C +0°C / -5°C

30 seconds

6°C/second max.

8 minutes max.

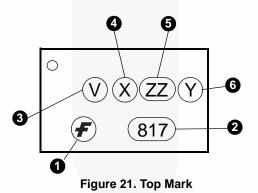
Ordering Information

Part Number	Package	Packing Method
FOD817X	DIP 4-Pin	Tube (100 units per tube)
FOD817XS	SMT 4-Pin (Lead Bend)	Tube (100 units per tube)
FOD817XSD	SMT 4-Pin (Lead Bend)	Tape and Reel (1,000 units per reel)
FOD817X300	DIP 4-Pin, DIN EN/IEC60747-5-5 option	Tube (100 units per tube)
FOD817X3S	SMT 4-Pin (Lead Bend), DIN EN/IEC60747-5-5 option	Tube (100 units per tube)
FOD817X3SD	SMT 4-Pin (Lead Bend), DIN EN/IEC60747-5-5 option	Tape and Reel (1,000 units per reel)
FOD817X300W	DIP 4-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 option	Tube (100 units per tube)

Note:

The product orderable part number system listed in this table also applies to the FOD814 products. "X" denotes the Current Transfer Ratio (CTR) options

Marking Information



Definiti	ons
1	Fairchild Logo
2	Device Number
3	DIN EN/IEC60747-5-5 Option (only appears on parts ordered with this option)
4	One-Digit Year Code, e.g., '5'
5	Two-Digit Work Week, Ranging from '01' to '53'
6	Assembly Package Code Y = Manufactured in Thailand YA = Manufactured in China

Carrier Tape Specifications

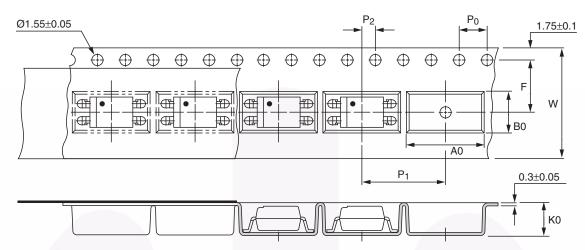
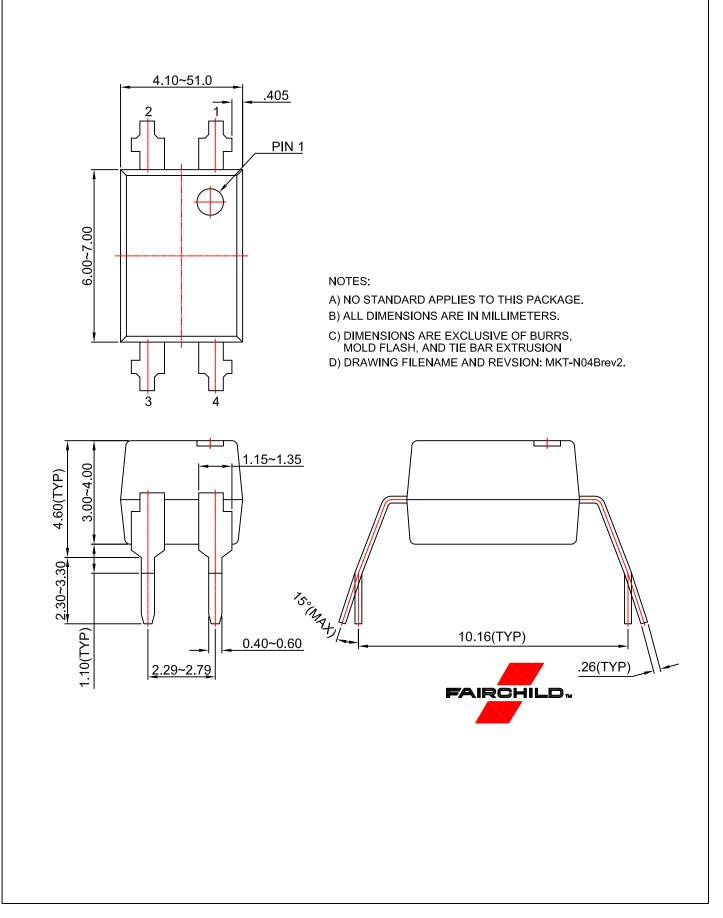
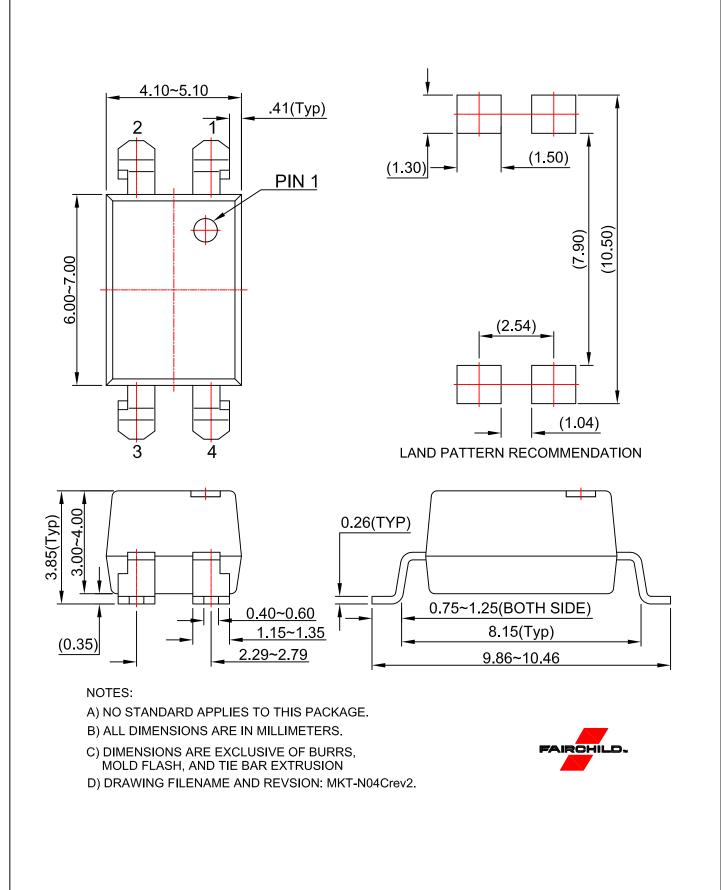
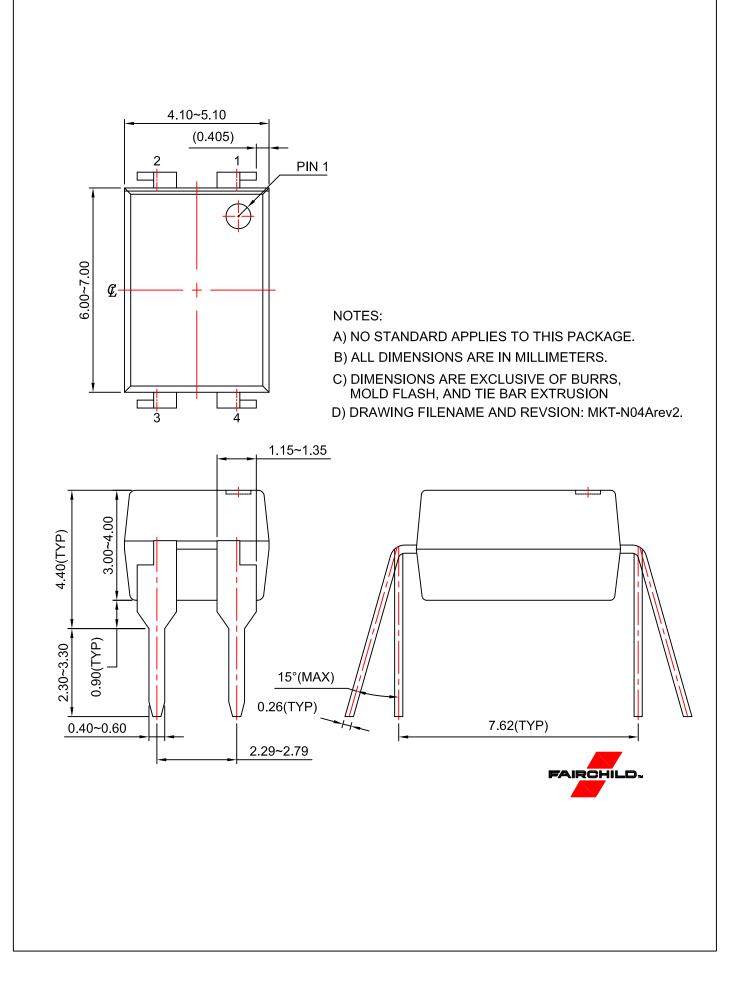


Figure 22. Carrier Tape Specification

Symbol	Description	Dimensions in mm (inches)
W	Tape wide	16 ± 0.3 (0.63)
P ₀	Pitch of sprocket holes	4 ± 0.1 (0.15)
F P ₂	Distance of compartment	7.5 ± 0.1 (0.295) 2 ± 0.1 (0.079)
P ₁	Distance of compartment to compartment	12 ± 0.1 (0.472)
A0	Compartment	10.45 ± 0.1 (0.411)
B0		5.30 ± 0.1 (0.209)
K0		4.25 ± 0.1 (0.167)







ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death a

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

FOD814AS FOD814A3S FOD814ASD FOD814A3SD FOD814A300 FOD814A FOD814A300W